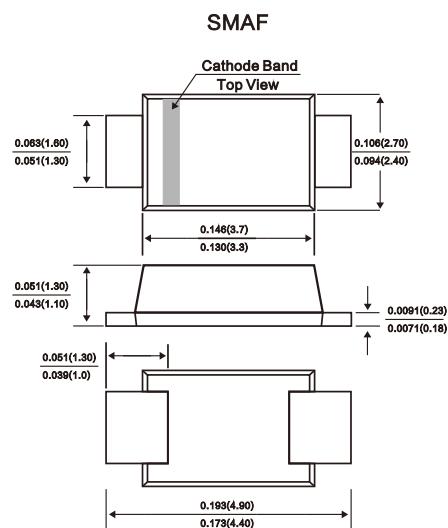


## Features

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



Dimensions in inches and (millimeters)

## MECHANICAL DATA

- Case: SMAF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 27mg / 0.00095oz

## Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

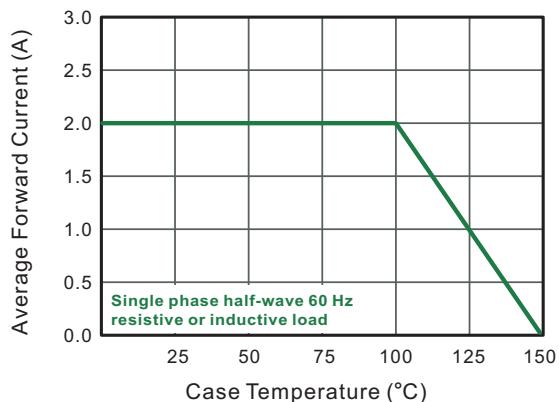
Parameter	Symbols	SS22F	SS24F	SS26F	SS28F	SS210F	SS212F	SS215F	SS220F	Units
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	20	40	60	80	100	120	150	200	
Maximum RMS voltage	V <sub>RMS</sub>	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	I <sub>F(AV)</sub>					2.0				V
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>			50				40		A
Max Instantaneous Forward Voltage at 2 A	V <sub>F</sub>	0.55		0.70		0.85		0.95		A
Maximum DC Reverse Current T <sub>a</sub> = 25°C at Rated DC Reverse Voltage T <sub>a</sub> = 100°C	I <sub>R</sub>	0.5	5		0.3	3				mV
Typical Junction Capacitance <sup>(1)</sup>	C <sub>j</sub>	160		80						A
Typical Thermal Resistance <sup>(2)</sup>	R <sub>θJA</sub>			80						°pF
Operating Junction Temperature Range	T <sub>j</sub>			-55 ~ +150						C/W
Storage Temperature Range	T <sub>stg</sub>			-55 ~ +150						°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

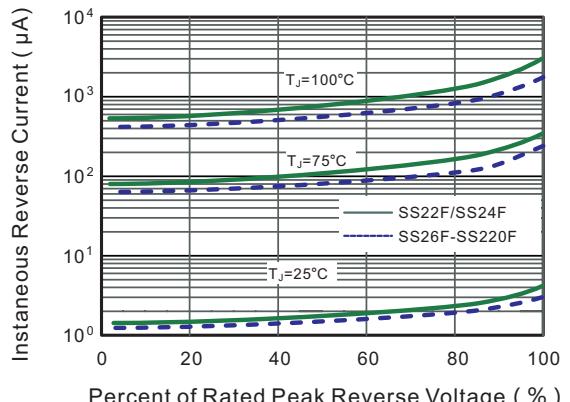
(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

°C

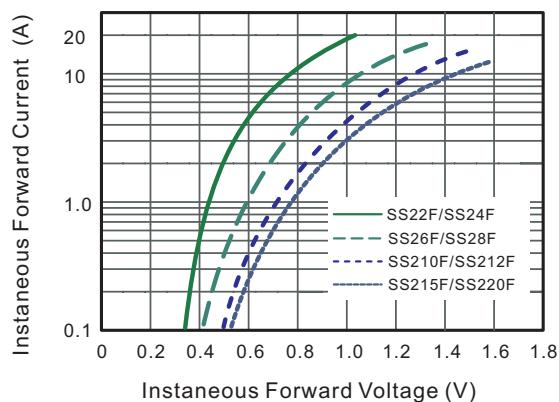
**Fig.1 Forward Current Derating Curve**



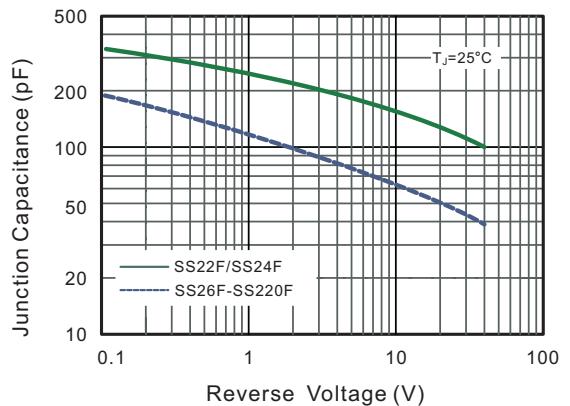
**Fig.2 Typical Reverse Characteristics**



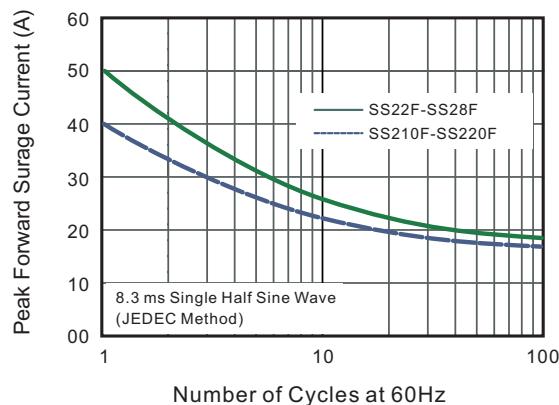
**Fig.3 Typical Forward Characteristic**



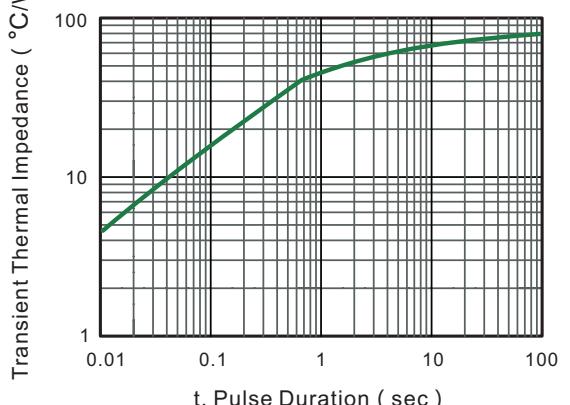
**Fig.4 Typical Junction Capacitance**



**Fig.5 Maximum Non-Repetitive Peak Forward Surge Current**



**Fig.6- Typical Transient Thermal Impedance**



单击下面可查看定价，库存，交付和生命周期等信息

[>>UMW\(友台半导体\)](#)